

74LVC1G14-Q100

Single Schmitt trigger inverter

Rev. 1 — 9 July 2012

Product data sheet

1. General description

The 74LVC1G14-Q100 provides the inverting buffer function with Schmitt trigger input. It is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The input can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment. Schmitt trigger action at the input makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V).
- $\pm 24\text{ mA}$ output drive ($V_{CC} = 3.0\text{ V}$)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Unlimited rise and fall times
- Input accepts voltages up to 5 V
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V ($C = 200\text{ pf}$, $R = 0\text{ }\Omega$)



3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator

4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74LVC1G14GW-Q100	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74LVC1G14GV-Q100	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753

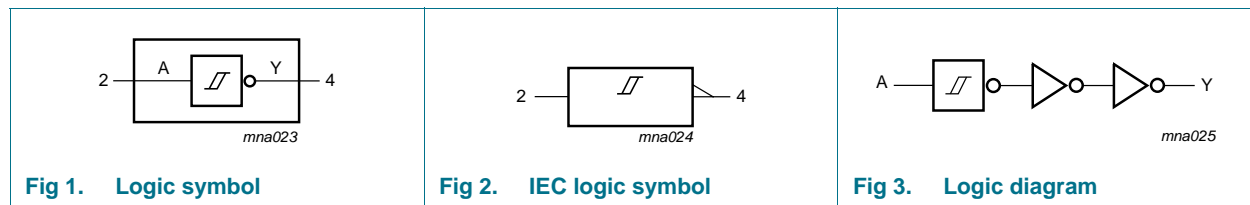
5. Marking

Table 2. Marking

Type number	Marking code ^[1]
74LVC1G14GW-Q100	VF
74LVC1G14GV-Q100	V14

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1 Pinning

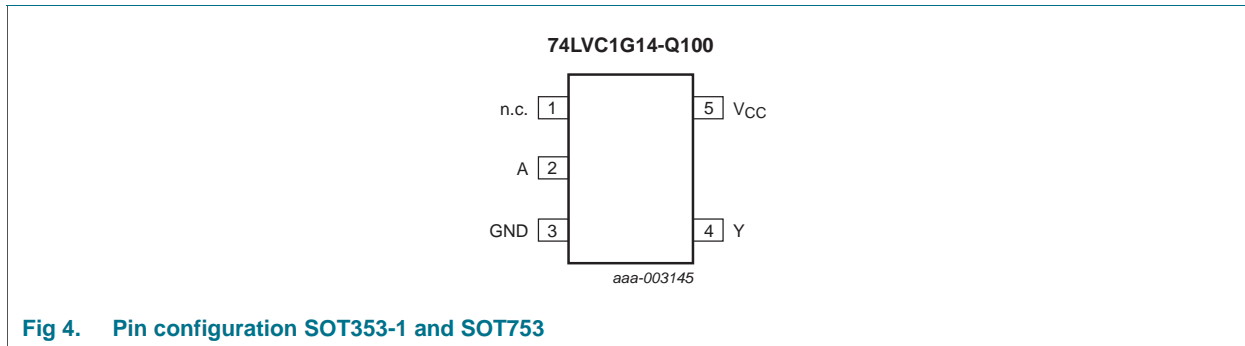


Fig 4. Pin configuration SOT353-1 and SOT753

7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
n.c.	1	not connected
A	2	data input
GND	3	ground (0 V)
Y	4	data output
V _{CC}	5	supply voltage

8. Functional description

Table 4. Function table^[1]

Input	Output
A	Y
L	H
H	L

[1] H = HIGH voltage level; L = LOW voltage level

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
V_I	input voltage		[1] -0.5	+6.5	V
V_O	output voltage	Active mode	[1][2] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
I_O	output current	$V_O = 0$ V to V_{CC}	-	±50	mA
I_{CC}	supply current		-	+100	mA
I_{GND}	ground current		-100	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[3] -	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
V_I	input voltage		0	-	5.5	V
V_O	output voltage	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC} = 0$ V	0	-	5.5	V
T_{amb}	ambient temperature		-40	-	+125	°C

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit					
			Min	Typ ^[1]	Max	Min	Max						
V_{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}	$V_{CC} - 0.1$	-	-	$V_{CC} - 0.1$	-	V					
		$I_O = -100$ μA; $V_{CC} = 1.65$ V to 5.5 V											
		$I_O = -4$ mA; $V_{CC} = 1.65$ V							1.2	1.54	-	0.95	-
		$I_O = -8$ mA; $V_{CC} = 2.3$ V							1.9	2.15	-	1.7	-
		$I_O = -12$ mA; $V_{CC} = 2.7$ V							2.2	2.50	-	1.9	-
		$I_O = -24$ mA; $V_{CC} = 3.0$ V							2.3	2.62	-	2.0	-
	$I_O = -32$ mA; $V_{CC} = 4.5$ V	3.8	4.11	-	3.4	-							

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-} I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.10	-	0.10	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	0.07	0.45	-	0.70	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	0.12	0.30	-	0.45	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	0.17	0.40	-	0.60	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	0.33	0.55	-	0.80	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	0.39	0.55	-	0.80	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±5	-	±100	μA
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0 V	-	±0.1	±10	-	±200	μA
I _{CC}	supply current	V _I = 5.5 V or GND; I _O = 0 A; V _{CC} = 1.65 V to 5.5 V	-	0.1	10	-	200	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 2.3 V to 5.5 V	-	5	500	-	5000	μA
C _I	input capacitance	V _{CC} = 3.3 V; V _I = GND to V _{CC}	-	5.0	-	-	-	pF

[1] All typical values are measured at maximum V_{CC} and T_{amb} = 25 °C.

Table 8. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 6](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{T+}	positive-going threshold voltage	see Figure 7 and Figure 8 V _{CC} = 1.8 V	0.82	1.0	1.14	0.79	1.14	V
		V _{CC} = 2.3 V	1.03	1.2	1.40	1.00	1.40	V
		V _{CC} = 3.0 V	1.29	1.5	1.71	1.26	1.71	V
		V _{CC} = 4.5 V	1.84	2.1	2.36	1.81	2.36	V
		V _{CC} = 5.5 V	2.19	2.5	2.79	2.16	2.79	V
		V _{T-}	negative-going threshold voltage	see Figure 7 and Figure 8 V _{CC} = 1.8 V	0.46	0.6	0.75	0.46
V _{CC} = 2.3 V	0.65			0.8	0.96	0.65	0.99	V
V _{CC} = 3.0 V	0.88			1.0	1.24	0.88	1.27	V
V _{CC} = 4.5 V	1.32			1.5	1.84	1.32	1.87	V
V _{CC} = 5.5 V	1.58			1.8	2.24	1.58	2.27	V

Table 8. Transfer characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 6](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see Figure 7 , Figure 8 and Figure 9						
		V _{CC} = 1.8 V	0.26	0.4	0.51	0.19	0.51	V
		V _{CC} = 2.3 V	0.28	0.4	0.57	0.22	0.57	V
		V _{CC} = 3.0 V	0.31	0.5	0.64	0.25	0.64	V
		V _{CC} = 4.5 V	0.40	0.6	0.77	0.34	0.77	V
		V _{CC} = 5.5 V	0.47	0.6	0.88	0.41	0.88	V

[1] All typical values are measured at T_{amb} = 25 °C

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 6](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t _{pd}	propagation delay	A to Y; see Figure 5 ^[2]						
		V _{CC} = 1.65 V to 1.95 V	1.0	4.1	11.0	1.0	14.0	ns
		V _{CC} = 2.3 V to 2.7 V	0.7	2.8	6.5	0.7	8.5	ns
		V _{CC} = 2.7 V	0.7	3.2	6.5	0.7	8.5	ns
		V _{CC} = 3.0 V to 3.6 V	0.7	3.0	5.5	0.7	7.0	ns
		V _{CC} = 4.5 V to 5.5 V	0.7	2.2	5.0	0.7	6.5	ns
C _{PD}	power dissipation capacitance	V _{CC} = 3.3 V; V _I = GND to V _{CC} ^[3]	-	15.4	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

13. Waveforms

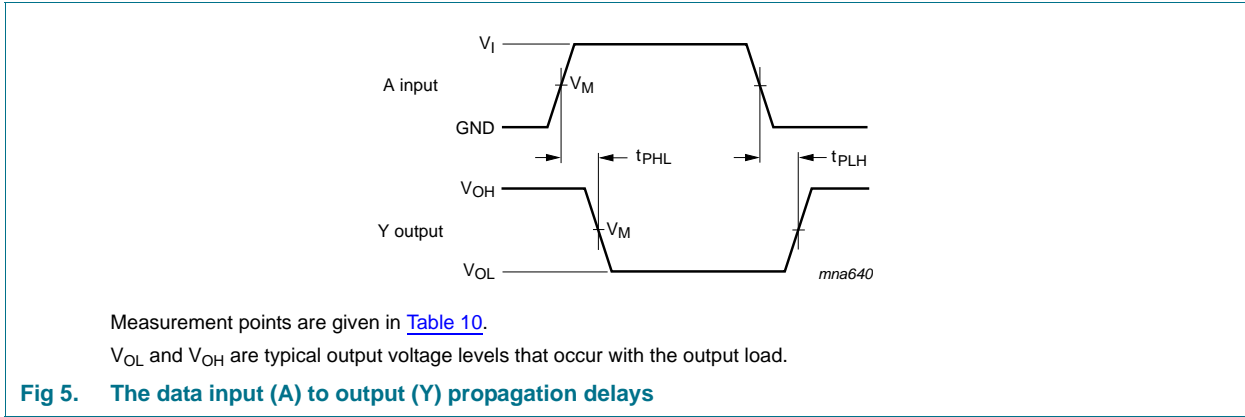


Table 10. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65 V to 1.95 V	$0.5V_{CC}$	$0.5V_{CC}$
2.3 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$

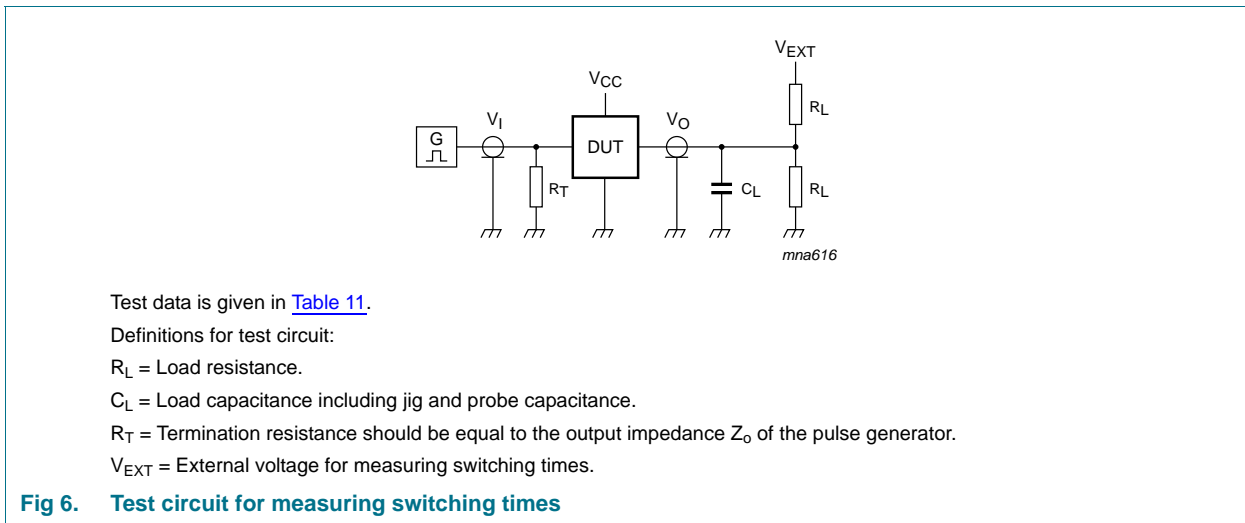
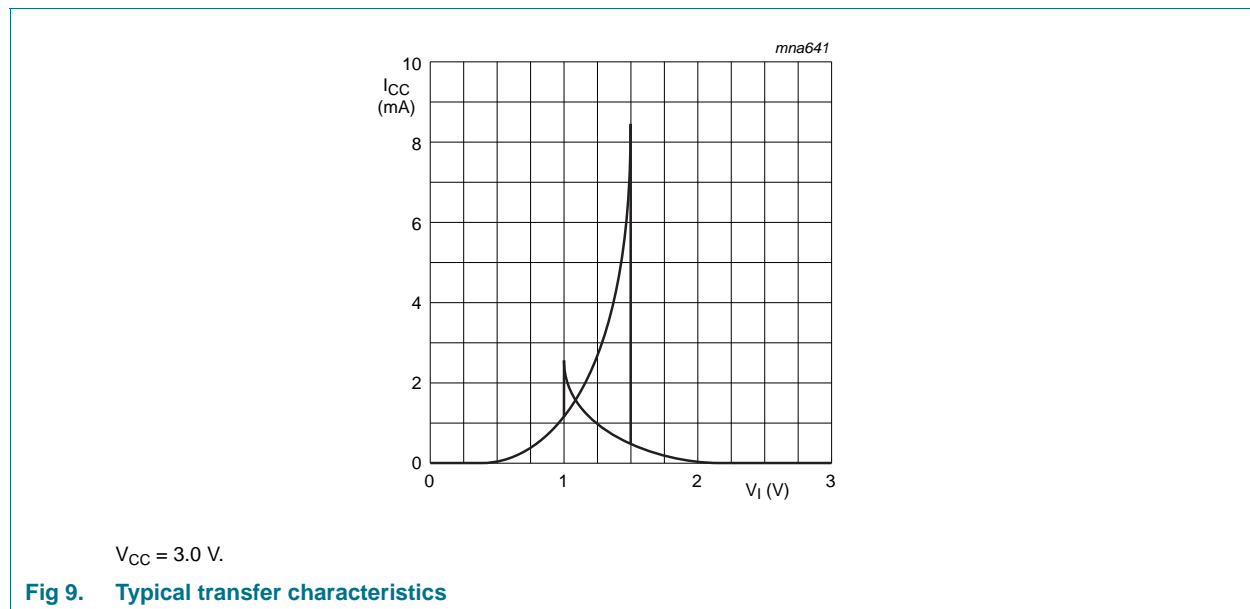
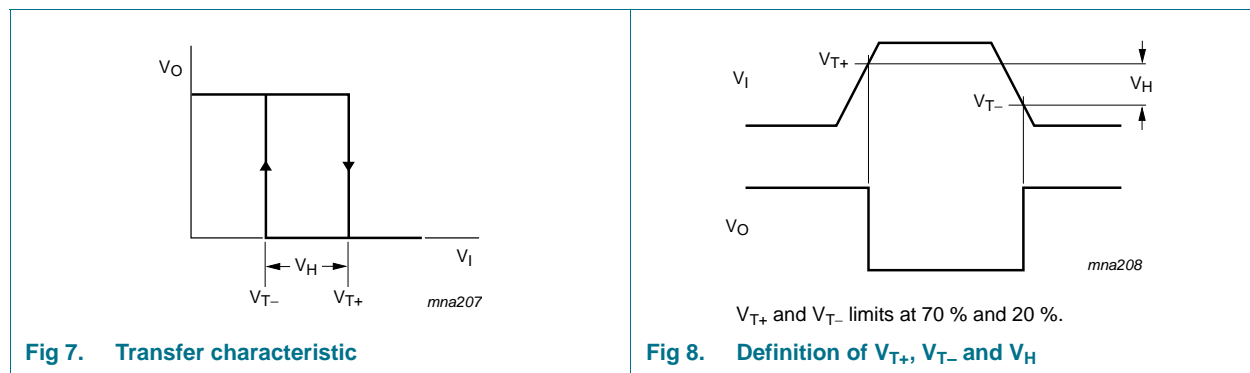


Table 11. Test data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	30 pF	1 k Ω	open
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V_{CC}	≤ 2.5 ns	50 pF	500 Ω	open

14. Waveforms transfer characteristics



15. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$$

P_{add} = additional power dissipation (μW);

f_i = input frequency (MHz);

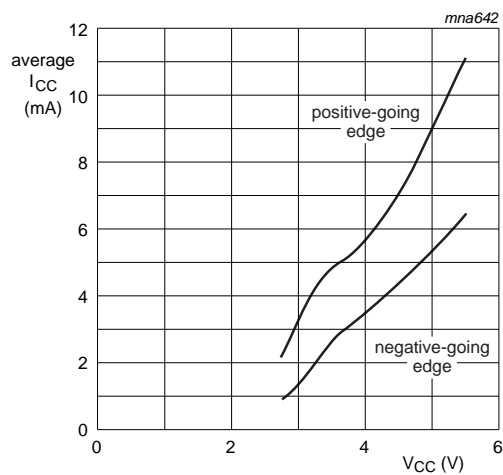
t_r = input rise time (ns); 10 % to 90 %;

t_f = input fall time (ns); 90 % to 10 %;

$\Delta I_{CC(AV)}$ = average additional supply current (μA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in [Figure 10](#).

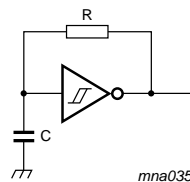
An example of a relaxation circuit using the 74LVC1G14-Q100 is shown in [Figure 11](#).



Linear change of V_I between 0.8 V to 2.0 V.

All values given are typical unless otherwise specified.

Fig 10. Average additional supply current as a function of supply voltage



$$f = \frac{1}{T} \approx \frac{1}{0.5 \times RC}$$

Fig 11. Relaxation oscillator

16. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

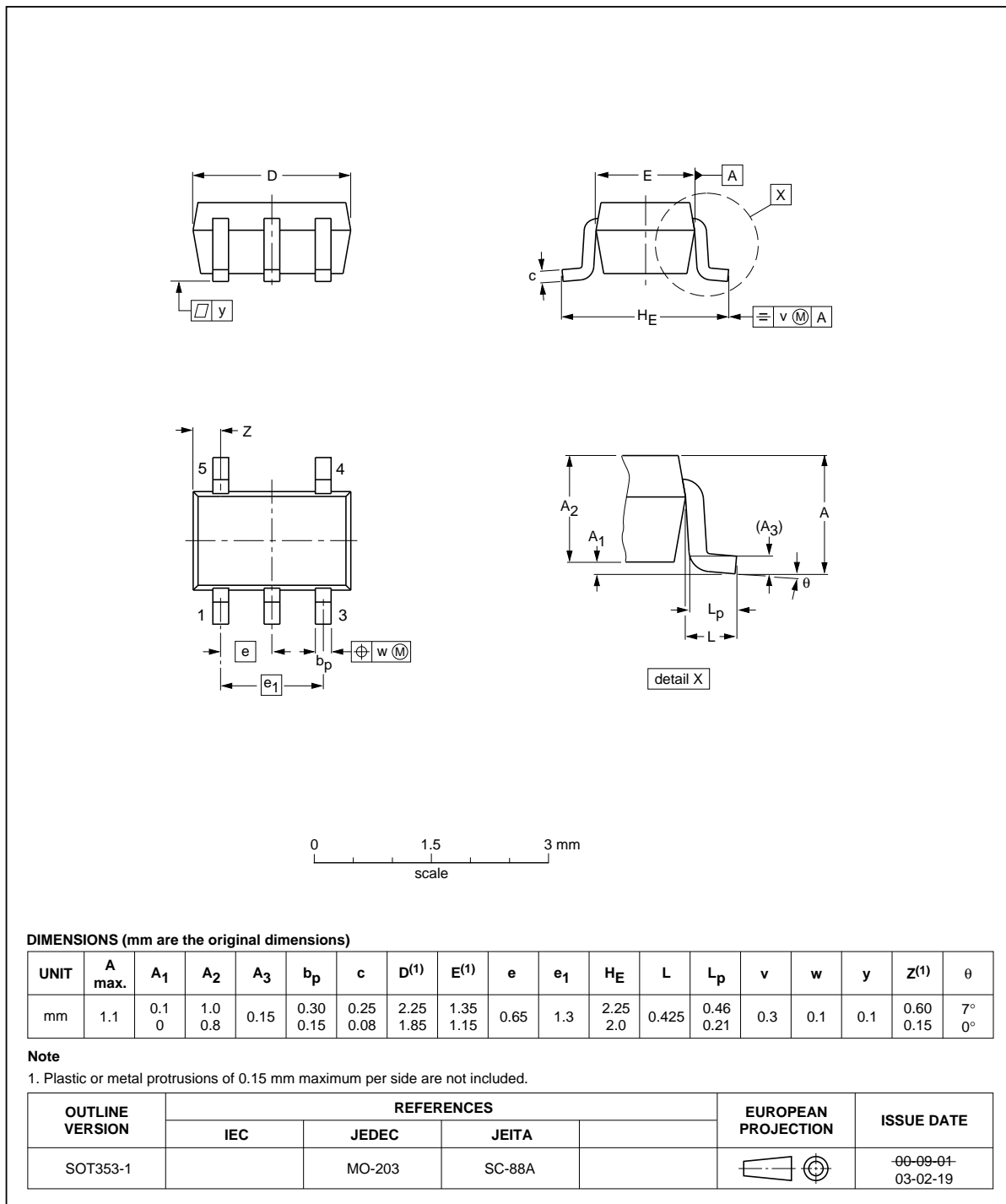


Fig 12. Package outline SOT353-1 (TSSOP5)

Plastic surface-mounted package; 5 leads

SOT753

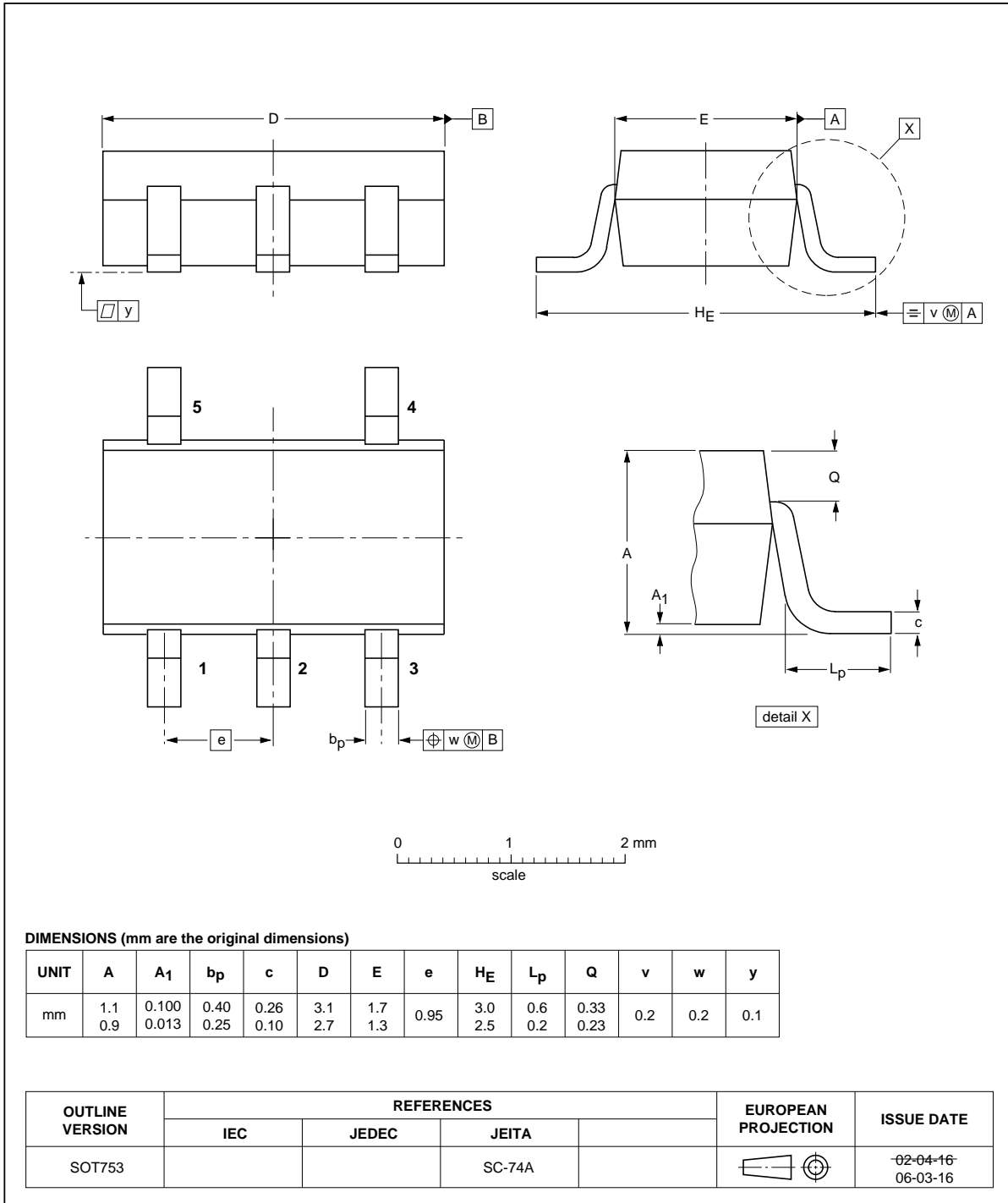


Fig 13. Package outline SOT753 (SC-74A)

17. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
TTL	Transistor-Transistor Logic
HBM	Human Body Model
ESD	ElectroStatic Discharge
MM	Machine Model
DUT	Device Under Test
MIL	Military

18. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G14_Q100 v.1	20120709	Product data sheet	-	-

19. Legal information

19.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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